

CONTENTS

	<i>Page</i>
Foreword J. R. O'CONNOR	ix
Preface J. R. O'CONNOR and J. SMILTENS	xi
Introductory Remarks C. E. RYAN	xv
Introductory Remarks W. SHOCKLEY	xviii

Section I: The Silicon-Carbon Binary System

Introduction	
F. N. RHINES	1
On the Theory of Gaseous Equilibria in the Silicon-Carbon Binary System	
J. SMILTENS	3
Thermodynamic Study of the Binary System Carbon-Silicon Using a Mass Spectrometer	
J. DROWART and G. DE MARIA	16
The Si-C and Ge-C Phase Diagrams	
R. I. SCACE and G. A. SLACK	24
Considerations of the Ternary System Carbon-Silicon-Germanium	
W. V. WRIGHT, Jr. and F. T. C. BARTELS	31
Review of Section I	
J. CHIPMAN	38

Section II: The Growth of Silicon Carbide Single Crystals

Introduction	
R. E. DAVIS	41
<i>1. The Growth of Silicon Carbide by Sublimation</i>	
Preparation and Properties of Pure Silicon Carbide	
D. R. HAMILTON	43
Formation of SiC Crystals from the Vapors	
ALLEN H. SMITH	53
Epitaxial and Single Crystal Growth on to Silicon Carbide Seeds	
K. M. HERGENROTHER, S. E. MAYER and A. I. MLAVSKY	60
<i>2. The Growth of Silicon Carbide by Gaseous Cracking</i>	
Growing of Silicon Carbide Crystals by Gaseous Cracking	
JAMES T. KENDALL	67
Crystal, Whisker and Microcrystalline Forms of Silicon Carbide	
KENNETH M. MERZ	73

Growth of β -Silicon Carbide Crystals by Gaseous Cracking	
VIRGIL E. STRAUGHAN and EDWARD F. MAYER	84
The Vapor Phase Growth of β -Silicon Carbide Single Crystals	
SHERMAN SUSMAN, R. SPENCER SPRIGGS and HAROLD S. WEBER	94
A Chemical Approach to the Synthesis of Silicon Carbide	
WALTER BRENNER	110
<i>3. The Growth of Silicon Carbide from Solutions</i>	
Growth of Silicon Carbide Crystals from Solution in Molten Metal Alloys	
F. A. HALDEN	115
Growth of Silicon Carbide from Solution	
RAY C. ELLIS, Jr.	124
Review of Section II	
P. H. KECK and M. TANENBAUM	130
Section III: Silicon Carbide as a Solid	
Introduction	
M. J. BUERGER	135
<i>1. The Crystal Structure of Silicon Carbide</i>	
Anomalous Silicon Carbide Structures	
H. JAGODZINSKI and H. ARNOLD	136
The Crystal Structure and Thermal Expansion of Cubic and Hexagonal Silicon Carbide	
A. TAYLOR and R. M. JONES	147
X-Ray Studies of Amorphous Carbon from Silicon Carbide	
FERDINAND EULER and ERNST R. CZERLINSKY	155
<i>2. The Surface Morphology of Silicon Carbide</i>	
Surface Features on Silicon Carbide Crystal Faces	
S. AMELINCKX and G. STRUMANE	162
Polytypism and Surface Structure of Silicon Carbide Crystals—Interferometric and X-ray Studies	
AJIT RAM VERMA	202
Morphology of Commercial Silicon Carbide Crystals	
ROBERT W. KEYES	217
<i>3. Chemical Imperfections in Silicon Carbide</i>	
Neutron Activation Analysis of Silicon Carbide	
LESTER F. LOWE, HARRIET D. THOMPSON and J. PAUL CALI	221
Analysis of Impurities in Silicon Carbide	
GEORGE H. MORRISON and RICHARD L. RUPP	227
<i>4. The Oxidation of Silicon Carbide</i>	
The Interaction of Oxygen with Silicon Carbide Surfaces	
J. A. DILLON, Jr.	235
The Kinetics of the Oxidation of Silicon Carbide	
PAUL J. JORGENSEN, MILTON E. WADSWORTH and IVAN B. CUTLER	241
General Comments on Section III	
W. SHOCKLEY	251
Review of Section III	
G. A. BUSCH	251

Section IV: Silicon Carbide as a Semiconductor

Introduction	
K. LEHOVEC	255
<i>1. Band Structure of Silicon Carbide</i>	
Simplified LCAO Method for Zinblende, Wurtzite, and Mixed Crystal Structures	
JOSEPH L. BIRMAN	257
Impurity Bands and Electroluminescence in Silicon Carbide <i>p-n</i> Junctions	
LYLE PATRICK and W. J. CHOYKE	281
Absorption of Light in Alpha Silicon Carbide near the Band Edge	
W. J. CHOYKE and LYLE PATRICK	306
<i>2. Electrical Properties of Silicon Carbide</i>	
Electrical Properties of Beta Silicon Carbide	
ROBERT G. POHL	312
Transient Conductivity of Black Silicon Carbide Aggregates	
EDWARD A. FAGEN	331
Resistivity of Granular Silicon Carbide—Impurity and Crystal Structure Dependence	
PAUL CARROLL	341
<i>3. Optical Properties of Silicon Carbide</i>	
Infra-red Properties of Silicon Carbide	
W. G. SPITZER, D. A. KLEINMAN, C. J. FROSCHE and D. J. WALSH	347
Intrinsic Optical Absorption in Single Crystal Silicon Carbide	
H. R. PHILIPP and E. A. TAFT	366
Infra-red Transmission of Alpha Silicon Carbide	
H. G. LIPSON	371
Minority Carrier Lifetime in Silicon Carbide by Carrier Injection Electroluminescence	
W. T. ERIKSEN	376
<i>4. Radiation Effects on Silicon Carbide</i>	
Aeolotropy of the Radiation-induced Expansions of Silicon Carbide	
WILLIAM PRIMAK	385
Effects of Fast Neutrons on Silicon Carbide	
L. W. AUKERMAN, H. C. GORTON, R. K. WILLARDSON and V. E. BRYSON	388
General Comments on Section IV	
W. SHOCKLEY	395
Review of Section IV Material	
R. W. KEYES	395
Review of Section IV (Continued)	
G. A. SLACK	398

Section V: Silicon Carbide Devices

Introduction	
I. A. LESK	400
<i>1. Processing of Silicon Carbide for Devices</i>	
The Etching of Silicon Carbide	
J. W. FAUST, Jr.	403
Phosphoric Acid and Fused Salt Etching of Silicon Carbide	
RAY C. ELLIS, Jr.	420

